

EVQ3367-R-00A

6 Channels, Max.150mA/Ch Boost WLED Driver With 15000:1 Dim Ratio And I2C

DESCRIPTION

The MPQ3367 is a step-up converter with 6-channel current sources. It is designed for driving the white LED arrays as backlighting of middle or small size LCD panel.

The MPQ3367 uses peak-current mode as its PWM control architecture to regulate the boost converter. 6 channel current sources are applied into the LED cathode to adjust the LED brightness. It regulates the current in each LED string to the value set by an external current-setting resistor, with 2.5% current regulation accuracy between strings.

MPQ3367 employs a low on-resistor MOSFET and a low headroom voltage design to get the higher efficiency. It has standard I²C digital interface for easy use. The switching frequency can be programmed by a resistor, I²C interface or external clock.

MPQ3367 provides analog/PWM/mix dimming mode with PWM input. Dimming mode can be selected by I²C interface or MIX/AD pin. It also has the phase shift function to eliminate the noise when PWM dimming.

Rich protections are designed to guarantee safety operation. The protection modes include OCP (over-current protection), OVP (over-voltage protection), OTP (over-temperature protection), LED short and open protection. Besides, the LED current decreases automatically at higher temperature.

The MPQ3367 is available in QFN24-4mmX4mm and TSSOP28-EP package.

ELECTRICAL SPECIFICATIONS

Parameter	Symbol	Value	Units
Input Voltage	V _{IN}	12	V
Output Voltage	VLED	<50	V
LEDs #		6 string	
LED Current /string	ILED	50	mA

FEATURES

- 3.5V to 36V Input Voltage Range
- 6 Channels with Max. 150mA per Channel
- Internal 100mΩ, 50V MOSFET
- Programmable Up to 2.2MHz Fsw
- External Sync SW Function
- Multi-Dimming Operation Mode thru PWM input Including:
 - 1. Direct PWM Dimming
 - 2. Analog Dimming
 - 3. Mix Dimming with 25%/12.5% transfer point
- 15000:1 Dim Ratio in PWM Dim at Fpwm≤200Hz
- 200:1 Dim Ratio at Analog Dim thru PWM Dim Signal Input.
- Excellent EMI Performance, Frequency Spread Spectrum
- I²C Interface
- Phase Shift Function for PWM Dimming
- 2.5% Current Matching
- Cycle by Cycle Current Limit
- Disconnect Vout from Vin
- LED Current Auto Decrement at High Temperature
- LED Short/Open, OTP, OCP, Inductor Short Protection
- Programmable LED Short Threshold
- Programmable OVP Threshold
- Fault Indicator Signal Output
- QFN24-4mmX4mm and TSSOP28-EP Package

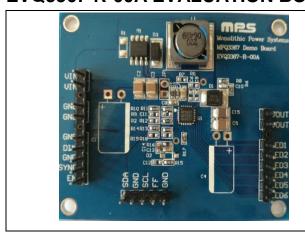
APPLICATIONS

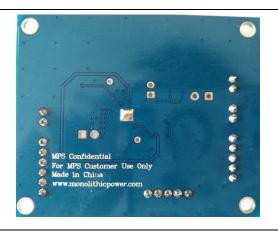
- Tablet/Notebook
- Auto-motive Display

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EVQ3367-R-00A EVALUATION BOARD

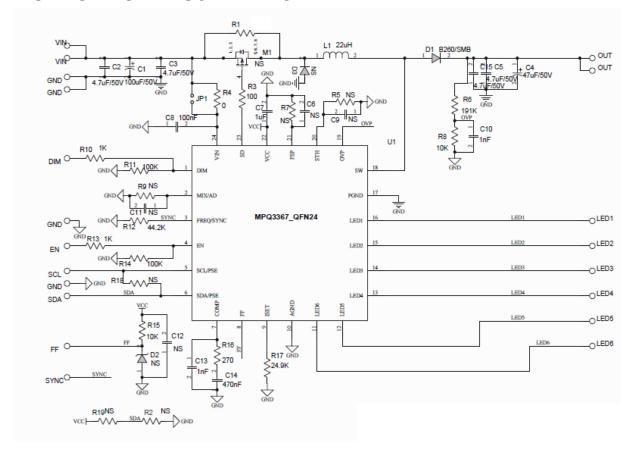




(L x W) 6.35cm x 5.25cm

Board Number	MPS IC Number		
EVQ3367-R-00A	MPQ3367GR		

EVALUATION BOARD SCHEMATIC



Typical Application for 6 Strings, 12 LED in series 50mA/string

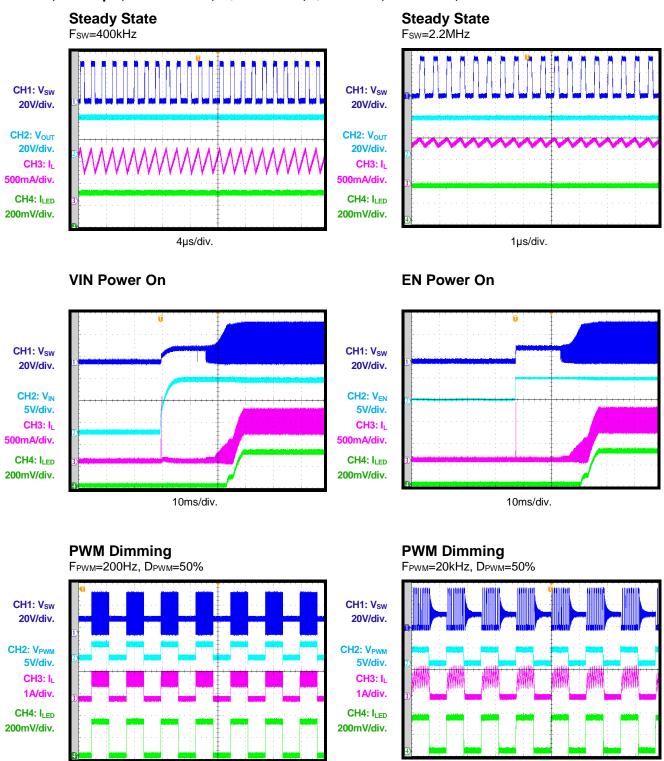


EVQ3367-R-00A BILL OF MATERIALS

,		L OF WATERIALS	1	Manufacturor	Part Number
Kei	value	•	Package	Manufacturer	Part Number
C1	NC	100μF/50V	DIP		
C2, C3, C5, C15	4.7µF/50V	Ceramic Capacitor; 50V;X7R;1210;	CAP/1210	muRata	GRM32ER71H475KA88L
C4	NC	Electrolytic Capacitor; 22µF/50V	DIP		
C7	1μF/25V	Ceramic Capacitor; 25V;X7R	CAP/0805	muRata	GRM216R61E105KA12D
C8	100nF/50V	Ceramic Capacitor; 50V;X7R	CAP/0603	TDK	C1608X7R1H104K
C6,C9, C11,C12	NC		CAP/0603		
C10	100pF/10V	50V;X7R	CAP/0603	muRata	GRM1885C1H101JA01D
C13	1nF/10V	16V;X7R	CAP/0603	muRata	GRM188R71102KA01D
C14	470nF/10V	16V;X7R	CAP/0603	TDK	C1608X7R1C474K
D1		Schottky Diode; 60V;2A;	DIODES /SMB	Diodes	B260
D2	NC	Zener Diode;3.3V	DIODES /SOD-123		
D3	WSCD24H	Schottky Diode; 40V;2A;	/SMA		WSCD24H
JP1	NC	Connector	CONN/DI P/2PIN/2. 54MM/A		
L1	22µH	Inductor;22µH;77.6m; Isat=3A	IND/TOK O/D104C- 919AS- 220M	ТОКО	D104C-919AS-220M
M1	AM4841P	P-Channel Mosfet; -40V/9A	MOS/SO8	Analog Power	AM4841P
R1	NC	Film Resistor;5%;	RES/1206		
R2,,R4, R5,R7, R9,R18	NC	Film Resistor;1%;	RES/0603		
R3	100Ω	Film Resistor;1%;	RES/0603	Yageo	RC0603FR-07100RL
R4	0	Film Resistor;1%;	RES/0603	Yageo	RC0603FR-070RL
R6	191kΩ	Film Resistor;1%;	RES/0603	Yageo	RC0603FR-07191KL
R8	10kΩ	Film Resistor;1%;	RES/0603	Yageo	RC0603FR-0710KL
R10, R13	1kΩ	Film Resistor;1%;	RES/0603	Yageo	RC0603FR-071KL
R11, R14,R15	100kΩ	Film Resistor;1%;	RES/0603	Yageo	RC0603FR-07100KL
R12	44.2kΩ	Film Resistor;1%;	RES/0603	Yageo	RC0603FR-0744K2L
R16	270Ω	Film Resistor;1%;	RES/0603	Yageo	RC0603FR-07270RL
R17	24.9kΩ	Film Resistor;1%;	RES/0603	Yageo	RC0603FR-0724K9L
VIN	TP1, TP2	Connector;	CONN/TP	_	0.54mm 400 da sura a
LED6	TP19	Connector;	CONN/TP		2.54mm 180 degree
U1	MPQ3367		QFN24	MPS	MPQ3367
	C2, C3, C5, C15 C4 C7 C8 C6,C9, C11,C12 C10 C13 C14 D1 D2 D3 JP1 L1 M1 R1, R2,,R4, R5,R7, R9,R18 R3 R4 R6 R8 R10, R13 R11, R14,R15 R12 R16 R17 VIN LED6	C1 NC C2, C3, C5, C15 4.7μF/50V C4 NC C7 1μF/25V C8 100nF/50V C6,C9, C11,C12 NC C10 100pF/10V C13 1nF/10V D1 NC D2 NC D3 WSCD24H JP1 NC L1 22μH M1 AM4841P R1 NC R2,,R4, R5,R7, R9,R18 NC R3 100Ω R4 0 R6 191kΩ R8 10kΩ R10, R13 1kΩ R11, R14,R15 100kΩ R16 270Ω R17 24.9kΩ VIN TP1, TP2 LED6 TP19	C1 NC Electrolytic Capacitor; 100μF/50V C2, C3, C5, C15 4.7μF/50V Ceramic Capacitor; 50V;X7R;1210; C4 NC Electrolytic Capacitor; 22μF/50V C7 1μF/25V Ceramic Capacitor; 25V;X7R C8 100nF/50V Ceramic Capacitor; 50V;X7R C6, C9, C11, C12 NC Ceramic Capacitor; 50V;X7R C10 100pF/10V Ceramic Capacitor; 16V;X7R C13 1nF/10V Ceramic Capacitor; 16V;X7R C14 470nF/10V Ceramic Capacitor; 16V;X7R D1 Schottky Diode; 60V;2A; D2 NC Zener Diode;3.3V D3 WSCD24H Schottky Diode; 40V;2A; JP1 NC Connector L1 22μH Inductor;22μH;77.6m; lsat=3A M1 AM4841P P-Channel Mosfet; -40V/9A R1 NC Film Resistor;5%; R2,R4, R5,R7, R9,R18 NC Film Resistor;1%; R3 100Ω Film Resistor;1%; R4 0 Film Resistor;1%; R8 10kΩ	C1 NC Electrolytic Capacitor; 100μF/50V DIP C2, C3, C5, C15 4.7μF/50V Ceramic Capacitor; 50V;X7R;1210; CAP/1210 C4 NC Electrolytic Capacitor; 22μF/50V DIP C7 1μF/25V Ceramic Capacitor; 25V;X7R CAP/0805 C8 100nF/50V Ceramic Capacitor; 50V;X7R CAP/0603 C6, C9, C11, C12 NC Ceramic Capacitor; 50V;X7R CAP/0603 C13 1nF/10V Ceramic Capacitor; 16V;X7R CAP/0603 C14 470nF/10V Ceramic Capacitor; 16V;X7R CAP/0603 D1 Schottky Diode; 60V;2A; 75MB DIODES 75MB D2 NC Zener Diode; 3.3V DIODES 75MB D3 WSCD24H Schottky Diode; 40V;2A; 75MB DIODES 75MB JP1 NC Connector DIODES 75MB JP1 NC Connector DIODES 75MB JP2 NC Zener Diode; 3.3V CONN/DIP 75MB JP2 NC Zener Diode; 3.3V DIODES 75MB JP2 NC Connector	C1 NC Electrolytic Capacitor; 100µF/50V DIP C2, C3, C5, C15 4.7µF/50V Ceramic Capacitor; 50V;X7R;1210; CAP/1210 muRata C4 NC Electrolytic Capacitor; 22µF/50V DIP DIP C7 1µF/25V Ceramic Capacitor; 25V;X7R CAP/0805 muRata C8 100nF/50V Ceramic Capacitor; 50V;X7R CAP/0603 TDK C6, C9, C11, C12 NC Ceramic Capacitor; 50V;X7R CAP/0603 muRata C10 100pF/10V Ceramic Capacitor; 16V;X7R CAP/0603 muRata C13 1nF/10V Ceramic Capacitor; 16V;X7R CAP/0603 TDK C14 470nF/10V Ceramic Capacitor; 16V;X7R CAP/0603 TDK D1 Schottky Diode; 60V;2A; 75MB DIODES 75MB Diodes D1 Schottky Diode; 60V;2A; 75MB DIODES 75MB Diodes D2 NC Zener Diode;3.3V DIODES 75MB JODES 75MB JP1 NC Connector P(2)PIN/22 JODES 75MB JODES 75MB JP2µH </td

EVB TEST RESULTS

Performance waveforms are tested on the evaluation board. $V_{IN} = 12V$, $L = 22\mu H$, LED=6P12S, F_{SW} =400kHz, I_{SET} =50mA, $T_A = 25$ °C, unless otherwise noted.

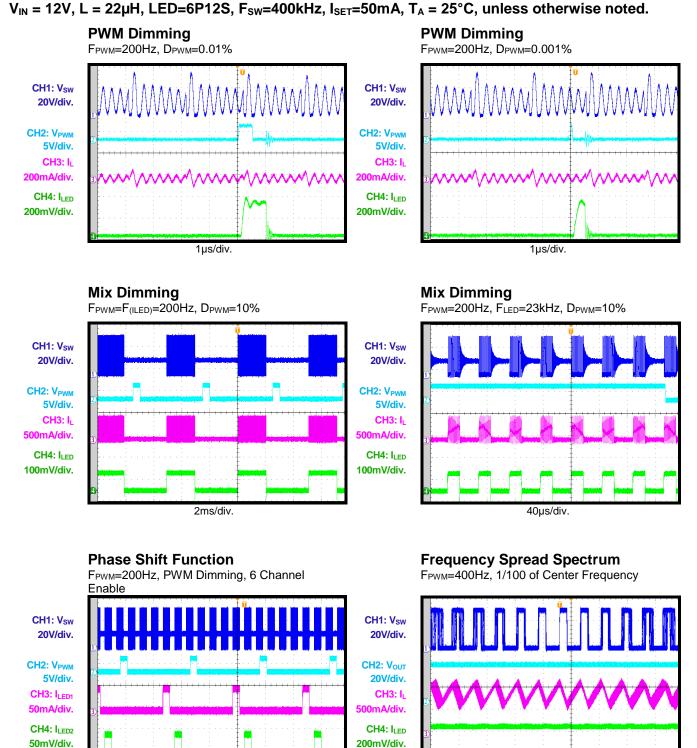


4ms/div.

40µs/div.

EVB TEST RESULTS (continued)

Performance waveforms are tested on the evaluation board.

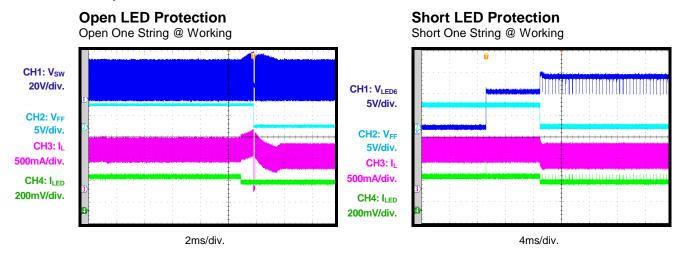


2ms/div.

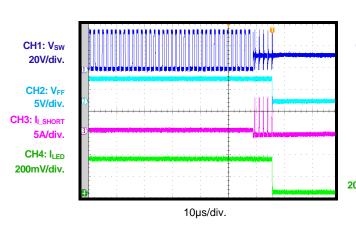
2µs/div.

EVB TEST RESULTS (continued)

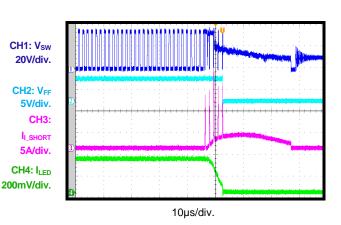
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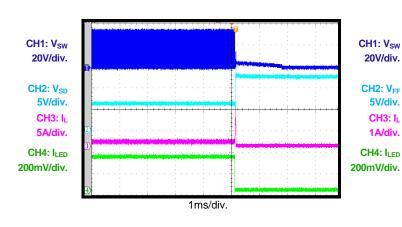
Short Inductor Protection



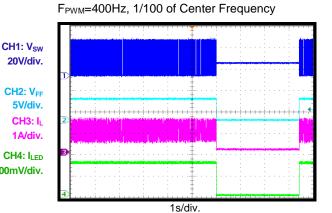
Short Diode Protection



Short VOUT to GND Protection



Thermal Shutdown Protection





PRINTED CIRCUIT BOARD LAYOUT

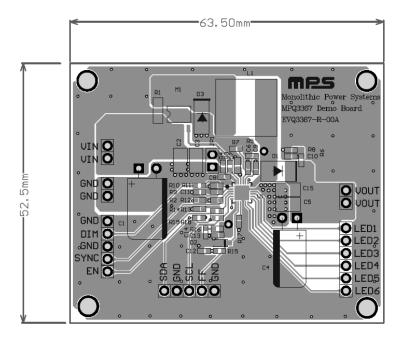


Figure 1—Top Layer

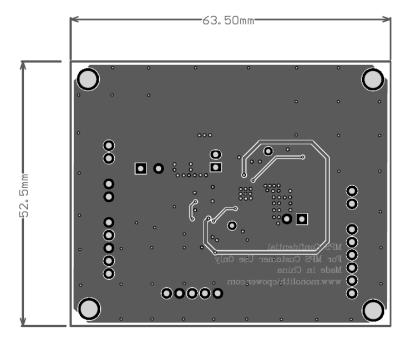


Figure 2—Bottom Layer



QUICK START GUIDE

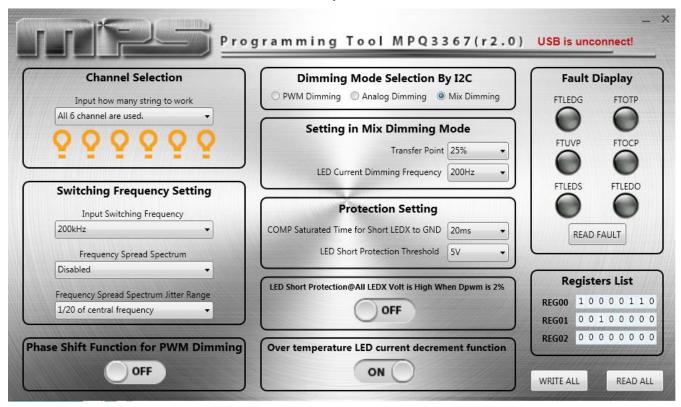
- 1. Provide a voltage source ranges from 3.5-36V between VIN terminal and GND on the EV board.
- 2. Connect the positive and negative terminals of the LED load (6 strings) to the LED+ and LED1~6 pins on the EV board, respectively.
- Drive EN pin high to enable the MPQ3367.
- 4. 100Hz~20kHz PWM pulse is added to the PWM terminal.
- 5. Please connect SCL, SDA and GND of EV board to SCL, SDA and GND of a I2C kit respectively.
- 6. Write and read the Registers.

Firstly, check that the I2C kit communicate with the computer normally. When the text "USB is unconnect" appear on the GUI, it indicates the I2C kit can not communicate the computer. Otherwise, the communication is OK.

Second, click the button to select the parameter.

Lastly, when users finish the parameter setting, send the data to IC until click the button "WRITE ALL".

User can also check the data is written to IC by click the button "READ ALL".



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